P-Channel 30-V (D-S) MOSFET

Key Features:

- Low r_{DS(on)} trench technology
- · Low thermal impedance
- · Fast switching speed

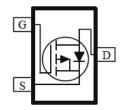
Typical Applications:

- · White LED boost converters
- Automotive Systems
- Industrial DC/DC Conversion Circuits

PRODUCT SUMMARY			
V _{DS} (V)	$r_{DS(on)}(m\Omega)$	I⊳(A)	
-30	57 @ V _{GS} = -4.5V	-3.9	
	89 @ V _{GS} = -2.5V	-3.2	







ABSOLUTE MAXIMUM RATINGS ($T_A = 25^{\circ}$ C UNLESS OTHERWISE NOTED)					
Parameter			Limit	Units	
Drain-Source Voltage			-30	V	
Gate-Source Voltage	V_{GS}	±8	V		
Continuous Drain Current ^a	T _A =25°C	I_	-3.9		
Continuous Drain Current	T _A =70°C	l _D	-3.1	Α	
Pulsed Drain Current ^b	I _{DM}	-10			
Continuous Source Current (Diode Conduction) a		I _S	-1.7	Α	
Power Dissipation ^a	T _A =25°C	P _D	1.3	W	
Prower Dissipation	T _A =70°C	' D	0.8	v v	
Operating Junction and Storage Temperature Range			-55 to 150	°C	

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Maximum	Units		
Maximum Junction-to-Ambient ^a	t <= 10 sec	$R_{ heta JA}$	100	°C/W		
Maximum Junction-to-Ambient	Steady State	IΛθΊΑ	166	C/VV		

Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

MI2339P

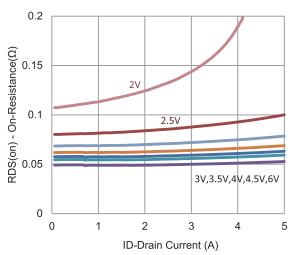
Electrical Characteristics

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
	Static					
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \text{ uA}$	-0.4			V
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 8 \text{ V}$			±100	nA
Zero Gate Voltage Drain Current		$V_{DS} = -24 \text{ V}, V_{GS} = 0 \text{ V}$			-1	uA
	DSS	$V_{DS} = -24 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			-25	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = -5 \text{ V}, V_{GS} = -4.5 \text{ V}$	-5			Α
Drain Source On Registence a	r	$V_{GS} = -4.5 \text{ V}, I_{D} = -2.5 \text{ A}$			57	mΩ
Drain-Source On-Resistance ^a	r _{DS(on)}	$V_{GS} = -2.5 \text{ V}, I_D = -2 \text{ A}$			89	
Forward Transconductance ^a	g _{fs}	$V_{DS} = -15 \text{ V}, I_{D} = -2.5 \text{ A}$		10		S
Diode Forward Voltage ^a	V_{SD}	$I_{S} = -0.9 \text{ A}, V_{GS} = 0 \text{ V}$		-0.8		V
		Dynamic ^b				
Total Gate Charge	Q_g	$V_{DS} = -15 \text{ V}, V_{GS} = -4.5 \text{ V},$		12		
Gate-Source Charge	Q_{gs}	$I_{D} = -2.5 \text{ A}$		1.9		nC
Gate-Drain Charge	Q_{gd}	I _D 2.5 A		3.6		
Turn-On Delay Time	t _{d(on)}	V_{DS} = -15 V, R_{L} = 6 Ω, I_{D} = -2.5 A, V_{GEN} = -4.5 V, R_{GEN} = 6 Ω		12		
Rise Time	t _r			9		ne
Turn-Off Delay Time	t _{d(off)}			42		ns
Fall Time	t _f	V GEN4.5 V, T GEN - 0 12		15		
Input Capacitance	C _{iss}			684		
Output Capacitance	C _{oss}	$V_{DS} = -15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		75		рF
Reverse Transfer Capacitance	C _{rss}			60		

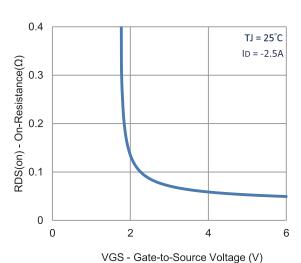
Notes

- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

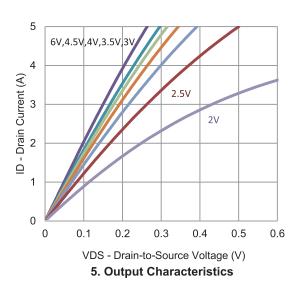
Typical Electrical Characteristics



1. On-Resistance vs. Drain Current



3. On-Resistance vs. Gate-to-Source Voltage

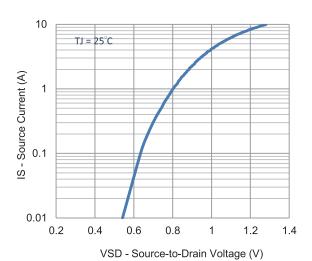


5
4
(V) TJ = 25°C

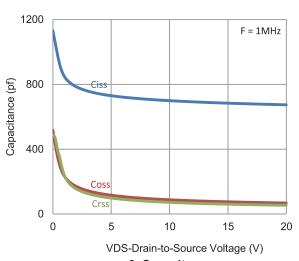
1
0
0
1
2
3

VGS - Gate-to-Source Voltage (V)

2. Transfer Characteristics

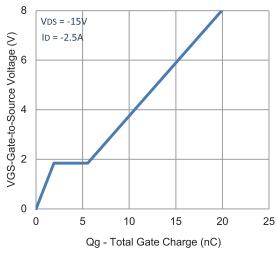


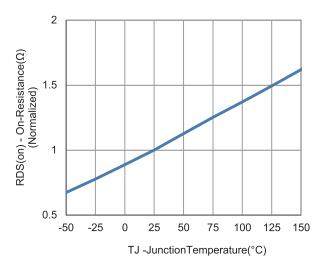
4. Drain-to-Source Forward Voltage



6. Capacitance

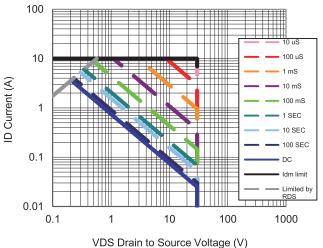


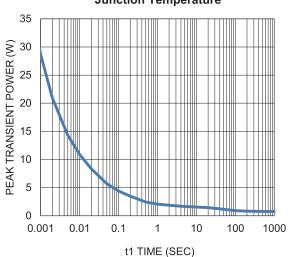




7. Gate Charge

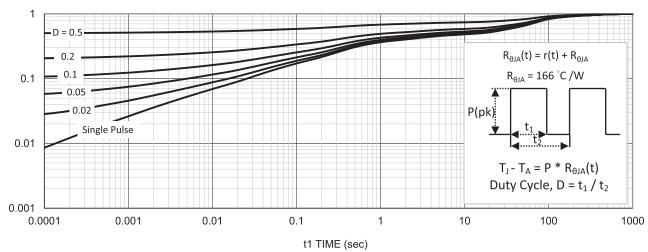






9. Safe Operating Area

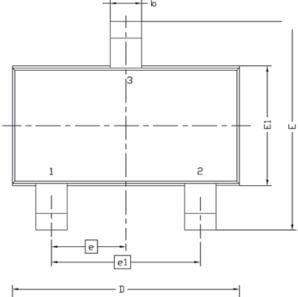
10. Single Pulse Maximum Power Dissipation



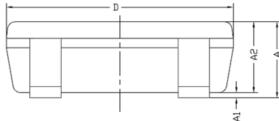
11. Normalized Thermal Transient Junction to Ambient

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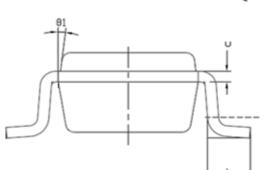
Package Information

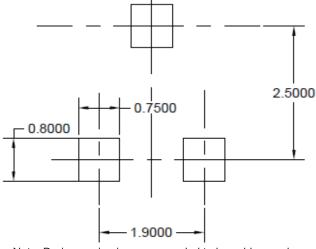


Symbol	MILLIMETERS		
Syllibol	MIN	MAX	
Α	0.8	1.2	
A1	0	0.1	
A2	0.7	1.1	
b	0.3	0.5	
С	0.1	0.2	
D	2.7	3.1	
Е	2.6	3	
E1	1.4	1.8	
е	0.95 BSC		
e1	1.9 BSC		
L	0.3	0.6	
θ1	7° NOM		



Recommended Pad Layout





Note: Drain opening is recommended to be solder mask defined in a copper fill for improved thermal performance

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